Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A



PRODUCT SUMMARY				
V _R	1200 V			
V _F (typical)	2.8 V			
t _{rr} (typical)	145 ns			
$I_{F(DC)}$ at T_C per leg	60 A at 86 °C			
$I_{F(AV)}$ at T_C per leg	60 A at 62 °C			

FEATURES

- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

The dual diode series configuration (HFA120FA120P) is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		1200	V	
Continuous forward current per leg	1_	T _C = 86 °C	60	A	
per module	I _F	1C = 60 C	120		
Single pulse forward current	I _{FSM}	T _J = 25 °C	350		
Maximum repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 60 $^{\circ}$ C	130		
	PD	T _C = 25 °C	337	w	
Maximum power dissipation		T _C = 100 °C	135	vv	
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 minute	2500	V	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-	
Forward voltage V _{FM}		I _F = 60 A	-	2.8	4.0	V
	I _F = 120 A	-	3.6	5.3		
	I _F = 60 A, T _J = 125 °C	-	2.7	-		
Reverse leakage current I _{RM}	$V_{R} = V_{R}$ rated	-	2.0	75	μA	
	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	2.7	10	mA	



COMPLIANT

HFA120FA120P



Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time t _{rr}		T _J = 25 °C		-	145	-	
	T _J = 125 °C		-	218	-	ns	
Peak recovery current I _{RRM}		T _J = 25 °C	I _F = 50 A dI _F /dt = - 200 A/μs V _R = 200 V	-	13	-	A
	IRRM	T _J = 125 °C		-	18	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	910	-	nC
		T _J = 125 °C		-	1920	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	Р		-	-	0.37	
Junction to case, both legs conducting	– R _{thJC}		-	-	0.185	°C/W
Case to heatsink	R _{thCS}	Flat, greased and surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm



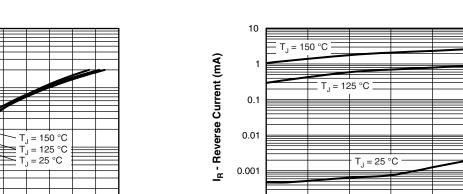
1000

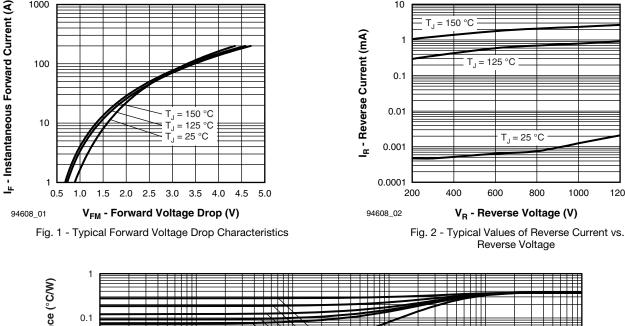
HFA120FA120P

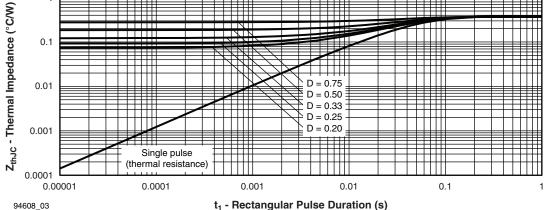
1200

HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A

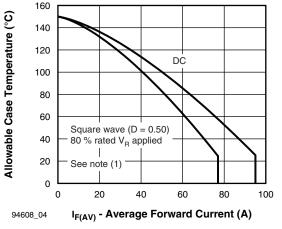
Vishay Semiconductors

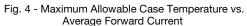


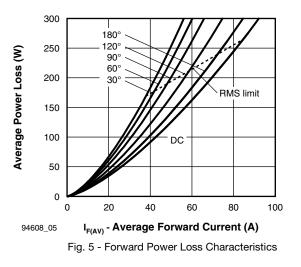








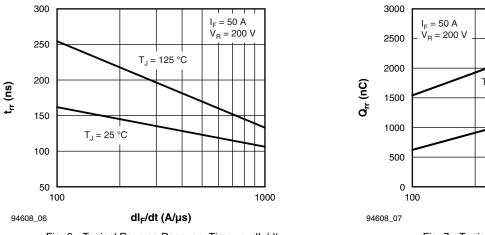




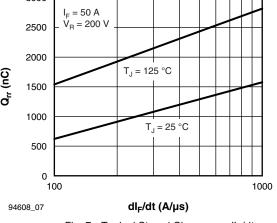
HFA120FA120P

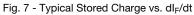
Vishay Semiconductors

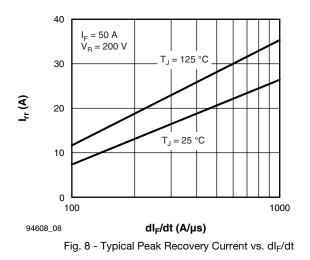
HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A











Note



HEXFRED[®] Ultrafast Soft Recovery Diode, 120 A

Vishay Semiconductors



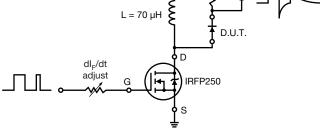


Fig. 9 - Reverse Recovery Parameter Test Circuit

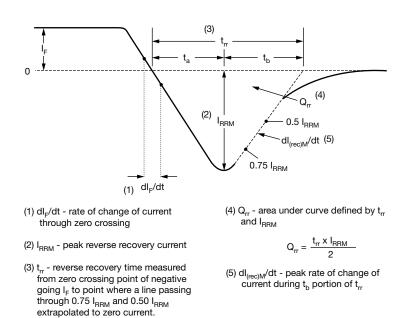


Fig. 10 - Reverse Recovery Waveform and Definitions

HFA120FA120P

Vishay Semiconductors

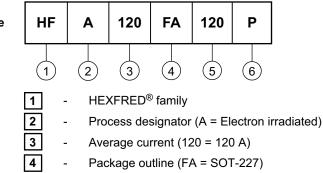
HEXFRED[®]



Ultrafast Soft Recovery Diode, 120 A

ORDERING INFORMATION TABLE

Device code

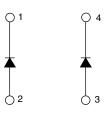


Package outline (FA = SOT-227)

- Voltage rating (120 = 1200 V)
- P = Lead (Pb)-free

5

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95036</u>					
Packaging information	www.vishay.com/doc?95037				



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.